Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	215782	(light near emitting near (device or diode or element))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:34
L2	168272	(laser near diode) or (semiconductor near laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:35
L3	10558	n-type near (electrode or contact or conduct$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:36
L4	10851	p-type near (electrode or contact or conduct$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:36
L5	18811	nitride near3 semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:37
L6	854	l1 and l3 and l4 and l5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:38
L7	699	l2 and l3 and l4 and l5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 16:38